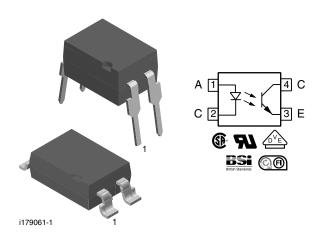
## SFH618A, SFH6186



Vishay Semiconductors

### **Optocoupler, Phototransistor Output, Low Input Current**



#### **DESCRIPTION**

The SFH618A (DIP) and SFH6186 (SMD) feature a high current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared diode emitter, which is optically coupled to silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 or SMD package.

The coupling devices are designed for signal transmission between two electrically separated circuits. The couplers are end-stackable with 2.54 mm lead spacing. Creepage and clearance distances of > 8 mm achieved with option 6.

#### **FEATURES**

 Good CTR linearity depending on forward current



- Low CTR degradation
- High collector emitter voltage, V<sub>CEO</sub> = 55 V
- Isolation test voltage, 5300 V<sub>RMS</sub>
- Low coupling capacitance
- End stackable, 0.100" (2.54 mm) spacing
- High common mode transient immunity
- Material categorization: For definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

### **APPLICATIONS**

- Telecom
- · Industrial controls
- · Battery powered equipment
- Office machines

#### AGENCY APPROVALS

- UL1577, file no. E52744 system code H or J, double protection
- CSA 93751
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1
- BSI IEC 60950; IEC 60065
- FIMKO

ORDERING INFORMATIO	N					
S F H 6 1 8 # - # X 0 # # T  PART NUMBER  CTR PACKAGE OPTION TAPE AND REEL  Option 7  Option 7  Option 9  > 0.7 mm						
AGENCY CERTIFIED/PACKAGE			R (%)			
	1 mA					
UL, CUL	63 to 125	100 to 200	160 to 320	250 to 500		
DIP-4	SFH618A-2	SFH618A-3	SFH618A-4	SFH618A-5		
DIP-4, 400 mil, option 6	=	SFH618A-3X006	-	=		
SMD-4, option 7	=	-	-	SFH618A-5X007T (1)		
SMD-4, option 9	SFH6186-2T <sup>(1)</sup>	SFH6186-3T <sup>(1)</sup> , SFH6186-3T1 <sup>(2)</sup> , SFH6186-3X002T <sup>(1)</sup>	SFH6186-4T <sup>(1)</sup>	SFH6186-5T <sup>(1)</sup> , SFH6186-5T1 <sup>(2)</sup>		
VDE, UL, CUL	63 to 125	100 to 200	160 to 320	250 to 500		
DIP-4	=	SFH618A-3X001	SFH618A-4X001	-		
DIP-4, 400 mil, option 6	=	SFH618A-3X016	SFH618A-4X016	SFH618A-5X016		
SMD-4, option 7	=	SFH618A-3X017T (1)	-	SFH618A-5X017T (1)		
SMD-4, option 9	-	SFH6186-3X001T (1)	SFH6186-4X001T	SFH6186-5X001T (1)		

#### Notes

- Additional options may be possible, please contact sales office
- (1) Also available in tubes, do not put T to the end
- (2) Product is rotated 180° in tape and reel cavity



## SFH618A, SFH6186

### Vishay Semiconductors

<b>ABSOLUTE MAXIMUM RA</b>	<b>ATINGS</b> ( $T_{amb} = 25  ^{\circ}C$ , unless ot	herwise specifie	ed)	
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		$V_{R}$	6	V
Power dissipation		P <sub>diss</sub>	70	mW
Forward current		I <sub>F</sub>	60	mA
ОUТРUТ				
Collector emitter voltage		V <sub>CEO</sub>	55	V
Emitter collector voltage		V <sub>ECO</sub>	7	V
Collector current		I <sub>C</sub>	50	mA
Collector current	t <sub>p</sub> ≤ 1 ms	I <sub>C</sub>	100	mA
Power dissipation		P <sub>diss</sub>	150	mW
COUPLER				
Isolation test voltage between emitter and detector	t = 1 s	V <sub>ISO</sub>	5300	V <sub>RMS</sub>
Isolation resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 25 °C	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω
isolation resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 100 °C	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω
Storage temperature range		T <sub>stg</sub>	- 55 to + 150	°C
Ambient temperature range		T <sub>amb</sub>	- 55 to + 100	°C
Junction temperature		T <sub>j</sub>	125	°C
Soldering temperature (1)	max. 10 s, dip soldering distance to seating plane ≥ 1.5 mm	T <sub>sld</sub>	260	°C

#### **Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
  implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
  maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

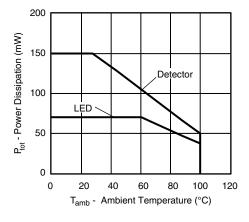


Fig. 1 - Permissible Power Dissipation vs. Ambient Temperature



# SFH618A, SFH6186

# Vishay Semiconductors

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	$I_F = 5 \text{ mA}$		$V_{F}$		1.1	1.5	V
Reverse current	V <sub>R</sub> = 6 V		I <sub>R</sub>		0.01	10	μA
Capacitance	$V_R = 0 V, f = 1 MHz$		Co		25		pF
Thermal resistance			R <sub>thja</sub>		1070		K/W
OUTPUT							
Collector emitter leakage current	V <sub>CE</sub> = 10 V		I <sub>CEO</sub>		10	200	nA
Collector emitter capacitance	V <sub>CE</sub> = 5 V, f = 1 MHz		C <sub>CE</sub>		7		pF
Thermal resistance			R <sub>thja</sub>		500		K/W
COUPLER							
	$I_{\rm C} = 0.32  \text{mA}, I_{\rm E} = 1  \text{mA}$	SFH618A-2 V <sub>CEsat</sub> 0.2	0.25	0.4	٧		
	IC = 0.32 IIIA, IF = 1 IIIA	SFH6186-2	V <sub>CEsat</sub>		0.25	0.4	٧
	$I_{\rm C} = 0.5  \text{mA}, I_{\rm F} = 1  \text{mA}$	SFH618A-3	V <sub>CEsat</sub>		0.25	0.4	٧
Collector emitter saturation	IC = 0.5 IIIA, IF = 1 IIIA	SFH6186-3	V <sub>CEsat</sub>	at 0.25	0.25	0.4	V
voltage	$I_C = 0.8 \text{ mA}, I_F = 1 \text{ mA}$	SFH618A-4	V <sub>CEsat</sub>		0.25	0.4	V
	IC = 0.0 IIIA, IF = 1 IIIA	SFH6186-4	V <sub>CEsat</sub>		0.25	0.4	٧
	I <sub>C</sub> = 1.25 mA, I <sub>E</sub> = 1 mA	SFH618A-5	V <sub>CEsat</sub>		0.25	0.4	V
	IC = 1.23 IIIA, IF = 1 IIIA	SFH6186-5	V <sub>CEsat</sub>		0.25	0.4	V
Coupling capacitance			C <sub>C</sub>		0.25		pF

#### Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
_	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	SFH618A-2	CTR	63		125	%
	$I_F = 1 \text{ mA}, V_{CE} = 0.5 \text{ V}$	SFH6186-2	CTR	63		125	%
	1 05 1 1 5 1	SFH618A-2	CTR	32	75		%
	$I_F = 0.5 \text{ mA}, V_{CE} = 1.5 \text{ V}$	SFH6186-2	CTR	32	75		%
	I= 1 mA V== 05 V	SFH618A-3	CTR	100		200	%
	$I_F = 1 \text{ mA}, V_{CE} = 0.5 \text{ V}$	SFH6186-3	CTR	100		200	%
	$I_F = 0.5 \text{ mA}, V_{CF} = 1.5 \text{ V}$	SFH618A-3	CTR	50	120		%
1 //	$I_F = 0.5 \text{ IIIA}, V_{CE} = 1.5 \text{ V}$	SFH6186-3	CTR	50	120		%
I <sub>C</sub> /I <sub>F</sub>	1 1 mA 1/ 0.5 1/	SFH618A-4	CTR	160		320	%
	$I_F = 1 \text{ mA}, V_{CE} = 0.5 \text{ V}$	SFH6186-4	CTR	160		320	%
	1 05 mA V 15 V	SFH618A-4	CTR	80	200		%
	$I_F = 0.5 \text{ mA}, V_{CE} = 1.5 \text{ V}$	SFH6186-4	CTR	80	200		%
	I <sub>F</sub> = 1 mA, V <sub>CE</sub> = 0.5 V	SFH618A-5	CTR	250		500	%
		SFH6186-5	CTR	250		500	%
	1 = 0.5 mA V	SFH618A-5	CTR	125	300		%
	$I_F = 0.5 \text{ mA}, V_{CE} = 1.5 \text{ V}$	SFH6186-5	CTR	125	300		%

<b>SWITCHING CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn on time	$V_{CC} = 5 \text{ V}, I_{C} = 2 \text{ mA}, R_{L} = 100 \Omega$	t <sub>on</sub>		6		μs
Rise time	$V_{CC} = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$	t <sub>r</sub>		3.5		μs
Turn off time	$V_{CC} = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$	t <sub>off</sub>		5.5		μs
Fall time	$V_{CC} = 5 \text{ V}, I_{C} = 2 \text{ mA}, R_{L} = 100 \Omega$	t <sub>f</sub>		5		μs





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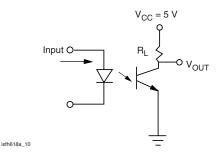


Fig. 2 - Test Circuit

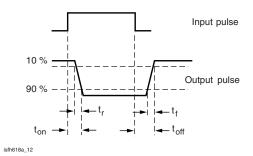


Fig. 3 - Test Circuit and Waveforms

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Climatic classification (according to IEC68 part 1)				55/100/21		
Comparative tracking index		CTI	175		399	
V <sub>IOTM</sub>			10000			V
V <sub>IORM</sub>			890			V
P <sub>SO</sub>					400	mW
I <sub>SI</sub>					275	mA
T <sub>SI</sub>					175	°C
Creepage distance	Standard DIP-4		7			mm
Clearance distance	Standard DIP-4		7			mm
Creepage distance	400 mil DIP-4		8			mm
Clearance distance	400 mil DIP-4		8			mm
Insulation thickness, reinforced rated	per IEC60950 2.10.5.1		0.4			mm

#### Note

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

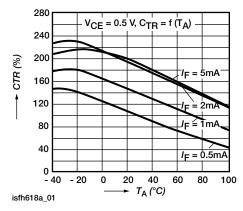


Fig. 4 - Current Transfer Ratio (typ.)

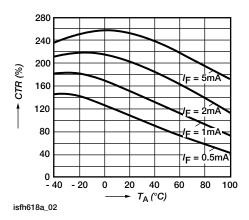


Fig. 5 - Current Transfer Ratio (typ.)

<sup>•</sup> As per IEC60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

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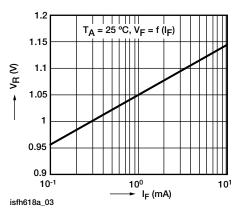


Fig. 6 - Diode Forward Voltage (typ.)

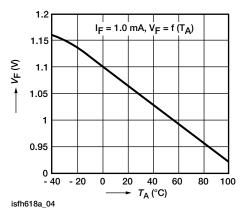


Fig. 7 - Diode Forward Voltage (typ.)

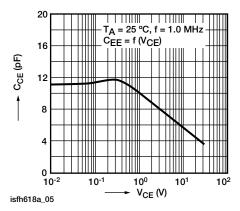


Fig. 8 - Transistor Capacitance

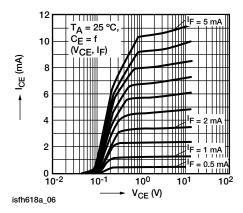


Fig. 9 - Output Characteristics

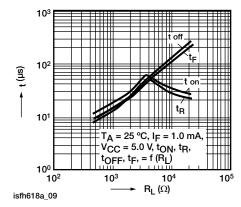
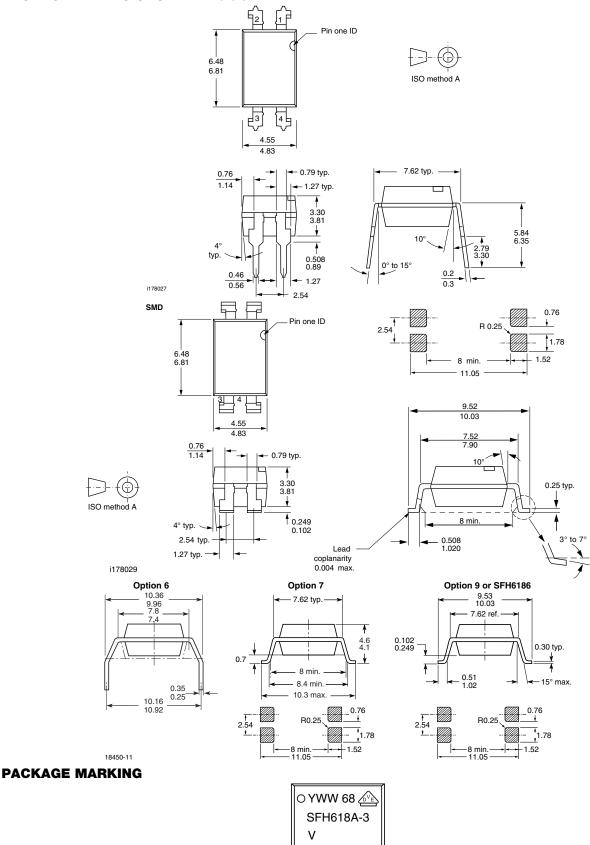


Fig. 10 - Switching Times (typ.)



## Vishay Semiconductors

### **PACKAGE DIMENSIONS** in millimeters





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